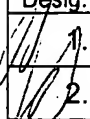
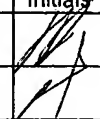



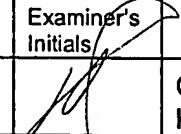


FORM HDP-1449 (Based on Form PTO-1449) PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE CITATION (Use several sheets if necessary) Sheet 1 of 1	ATTORNEY DOCKET NO.	SERIAL NO.
	9319G-000650	to be assigned
	APPLICANT	
	Takamitsu HIGUCHI et al	
	FILING DATE	GROUP
	herewith	unknown

U.S. PATENT DOCUMENTS						
Ref. Desig.	Examiner's Initials	Document Number	Date	Name	Class/ Subclass	(If appropriate) Filing Date
1.		5,824,419	10/20/1998	Kawai et al		
2.		6,203,860	03/20/2001	Kawai et al		

FOREIGN PATENT DOCUMENTS						
Ref. Desig.	Examiner's Initials	Document Number	Date	Country	Class/ Subclass	Translation * Yes No
1.		2001-196892	7/19/2001	Japan		Abstract
2.		2001-185988	7/6/2001	Japan		Abstract
3.		2001-068964	3/16/2001	Japan		Abstract

OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)						
Ref. Desig.	Examiner's Initials					
1.		Christen, H.-M. et al, "The growth and properties of epitaxial KNbO3 thin films and KNbOe/KTaOe superlattices", Appl. Phys. Lett 68, 11 March 1996, pages 1488-1490.				

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